

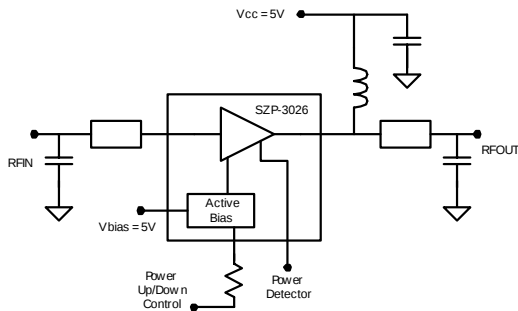


Product Description

Sirenza Microdevices' SZP-3026Z is a high linearity single stage class AB Heterojunction Bipolar Transistor (HBT) amplifier housed in a proprietary surface-mountable plastic encapsulated package. This HBT amplifier is made with InGaP on GaAs device technology and fabricated with MOCVD for an ideal combination of low cost and high reliability.

This product is specifically designed as a flexible final or driver stage for 802.16 equipment in the 3.0-3.8GHz bands. It can run from a 3V to 6V supply. It is prematched to ~5 ohms on the input for broadband performance and ease of matching at the board level. It features an output power detector, on/off power control, ESD protection, excellent overall robustness and a proprietary hand reworkable and thermally enhanced SOF-26 package. This product features a RoHS Compliant and Green package with matte tin finish, designated by the 'Z' suffix.

Functional Block Diagram



Key Specifications

Symbol	Parameters: Test Conditions, 3.4-3.6GHz, 5V App circuit, $Z_0 = 50\Omega$, $V_{CC} = 5.0V$, $I_q = 385mA$, $T_{BP} = 30^\circ C$	Unit	Min.	Typ.	Max.
f_O	Frequency of Operation	MHz	3000		3800
P_{1dB}	Output Power at 1dB Compression – 3.5GHz	dBm	31.7	33.2	
S_{21}	Small Signal Gain – 3.5GHz	dB	10.5	12.0	
Pout	EVM (802.11g 54Mb/s) at Pout=26dBm - 3.5GHz	%		2.5	
IM3	Third Order Suppression (Pout=23dBm per tone) - 3.5GHz	dBc		-43	-40
NF	Noise Figure at 3.5GHz	dB		5.1	
IRL	Worst Case Input Return Loss 3.4-3.6GHz	dB	14	18	
ORL	Worst Case Output Return Loss 3.4-3.6GHz		7	10	
Vdet Range	Output Voltage Range for Pout=10dBm to 33dBm	V		0.9 to 2.2	
I_{cq}	Quiescent Current ($V_{CC} = 5V$)	mA	347	385	424
I_{VPC}	Power Up Control Current ($V_{PC}=5V$)	mA		2.3	
I_{leak}	V_{CC} Leakage Current ($V_{CC} = 5V$, $V_{PC} = 0V$)	μA			10
$R_{th, j-l}$	Thermal Resistance (junction - lead)	$^\circ C/W$		12	

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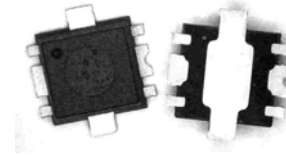
Phone: (800) SMI-MMIC

<http://www.sirenza.com>
EDS-104666 Rev F

Preliminary

SZP-3026Z

3.0-3.8GHz 2W InGaP Amplifier



Proprietary SOF-26 Package

Product Features

- **$P_{1dB} = 33.6dBm @ 5V$**
- **802.11g 54Mb/s Class AB Performance**
 $P_{out} = 26dBm @ 2.5\% EVM$, $V_{CC} 5V$, 570mA
 $P_{out} = 27dBm @ 2.5\% EVM$, $V_{CC} 6V$, 513mA
On-chip Output Power Detector
- **Input Prematched to ~5 ohms**
- **Proprietary Low Thermal Resistance Package**
Hand Solderable and Easy Rework
- **Power up/down control < 1 μs**

Applications

- **802.16 WiMAX Driver or Output Stage**
- **WLL**



Preliminary

SZP-3026Z 3.0-3.8GHz 2W Power Amp

Typical 5V Performance with Appropriate App Circuit (Vcc=5V, Icq=385mA, * 802.11g 54Mb/s)

Parameter	Units	3.0GHz	3.3GHz	3.4GHz	3.5GHz	3.6GHz	3.7GHz	3.8GHz
Gain@Pout=26dBm	dB	12.4	12.4	12.4	12.2	12.0	11.5	11.0
P1dB	dBm	33.9	33.9	33.6	33.2	32.9	32.6	32.1
Pout @ 2.5% EVM*	dBm	26.5	26.5	26.5	26.0	25.5	25.5	25
Current @ Pout 2.5% EVM*	mA	590	580	580	570	560	560	550
Input Return Loss	dB	21.8	21.8	20.6	19.6	18.3	15.9	15.9
Output Return Loss	dB	9.0	9.0	10.0	11.2	11.7	10.3	10.3

Pin Out Description

Pin #	Function	Description
1	VBIAS	This is the supply voltage for the active bias circuit.
2	RFIN	This is the RF input pin and has a DC voltage present. An external DC block is required.
3	VPC	Power up/down control pin. The voltage on this pin should never exceed the voltage on pin 1 by more than 0.5V unless the supply current from pin 3 is limited < 10mA.
4	VDET	This is the output port for the power detector. It samples the power at the input of the amplifier.
5	RFOUT/VCC	This is the RF output pin and DC connection to the collector.
6	NC	This pin is not connected internal to the package. Buss it to pin 5 as shown on the app circuit to achieve the specified performance.
GND	GND	These pins are DC connected to the backside paddle. They provide good thermal connection to the backside paddle for hand soldering and rework. Many thermal and electrical GND vias are recommended as shown in the landing pattern.

Absolute Maximum Ratings

Parameters	Value	Unit
VC1 Collector Bias Current (I _{VC1})	1500	mA
**Device Voltage (V _{CC})	7.0	V
Power Dissipation	6	W
Operating Lead Temperature (T _L)	-40 to +85	°C
*Max RF output Power for 50 ohm continuous long term operation	30	dBm
Max RF Input Power for 50 ohm output load	27	dBm
Max RF Input Power for 10:1 VSWR output load	23	dBm
Storage Temperature Range	-40 to +150	°C
Operating Junction Temperature (T _J)	+150	°C
ESD Human Body Model	1000	V

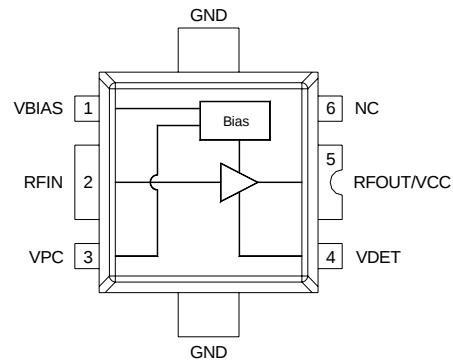
Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias conditions should also satisfy the following expression:
 $I_D V_D < (T_J - T_L) / R_{TH}$ j-l

* With specified application circuit.

** No RF Drive

Simplified Device Schematic



Caution: ESD Sensitive

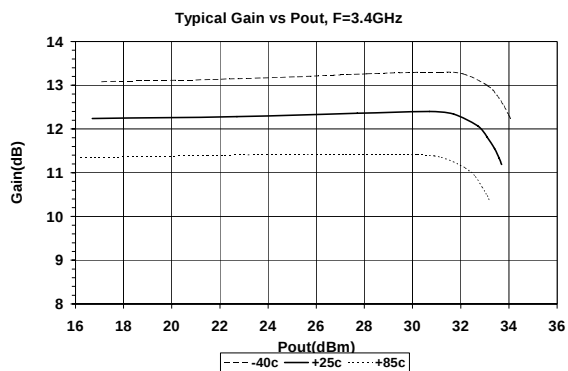
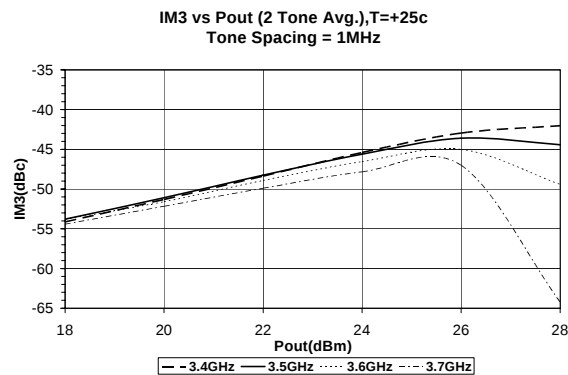
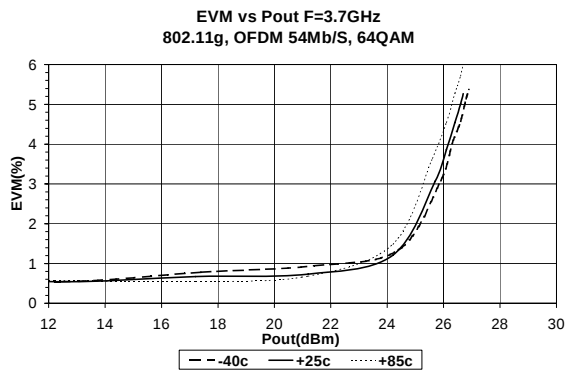
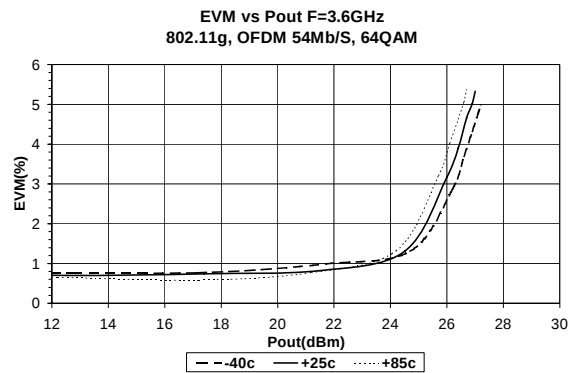
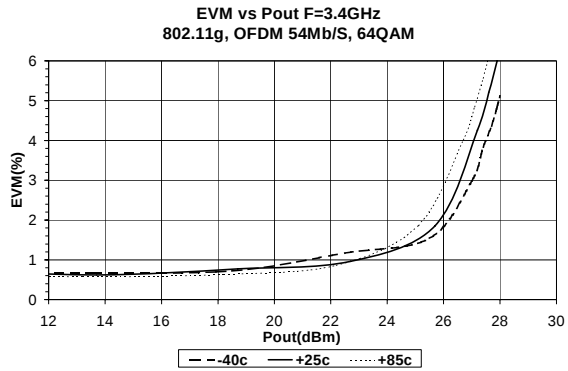
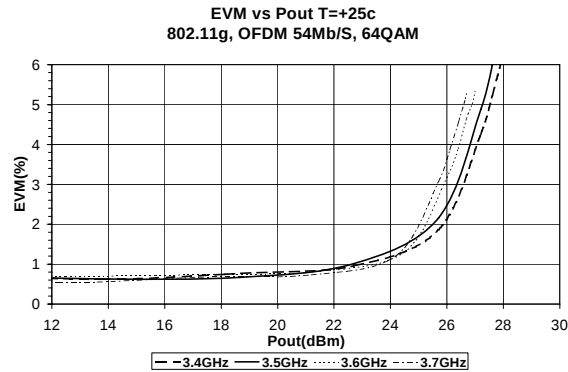
Appropriate precaution in handling, packaging and testing devices must be observed.



Preliminary
SZP-3026Z 3.0-3.8GHz 2W Power Amp

Measured 3.4-3.6 GHz, 5V Application Circuit Data ($V_{cc} = V_{pc} = 5.0V$, $I_q = 385mA$, $T=25C$)

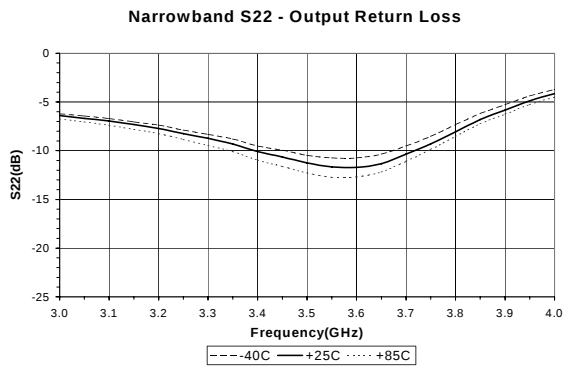
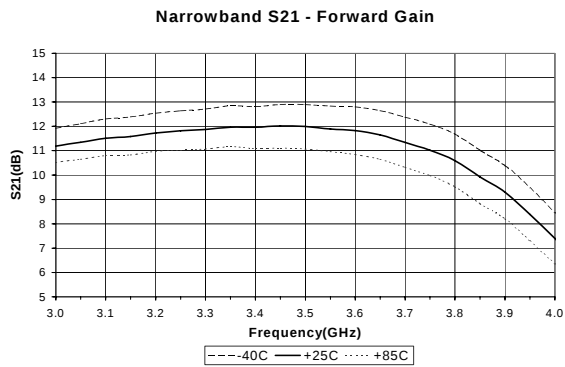
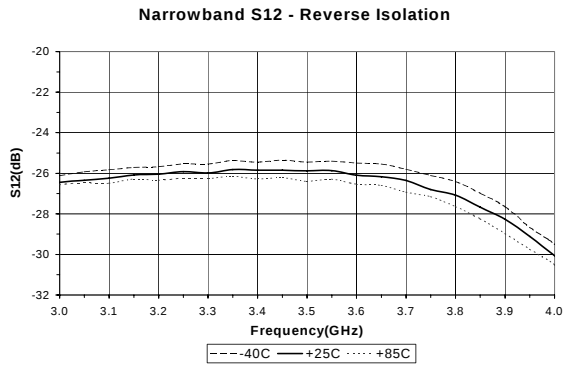
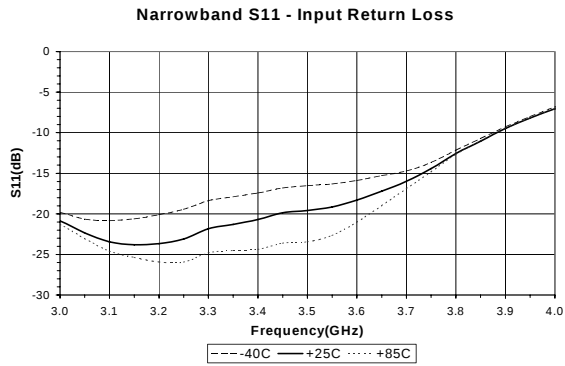
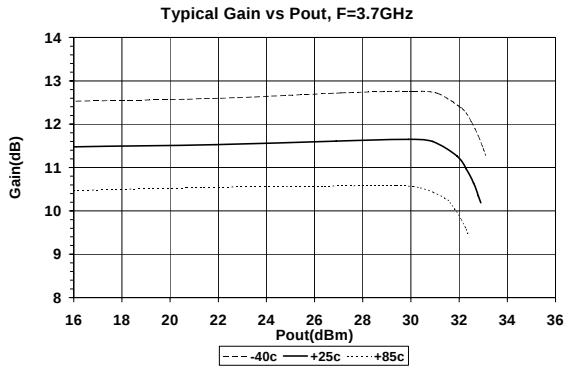
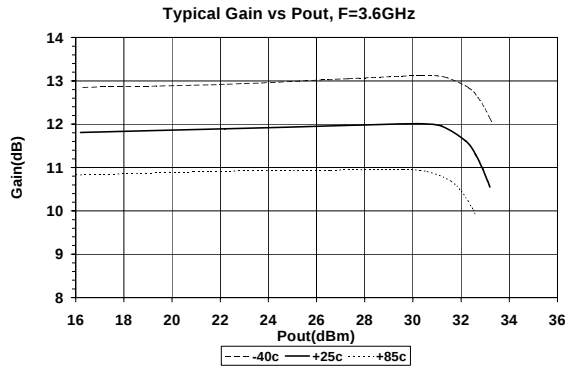
Source EVM = 0.6%, not deembedded from data.





Preliminary
SZP-3026Z 3.0-3.8GHz 2W Power Amp

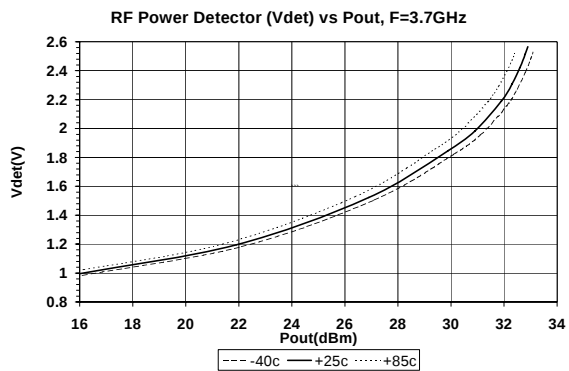
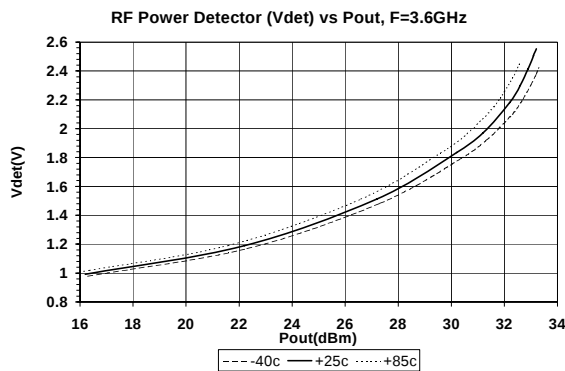
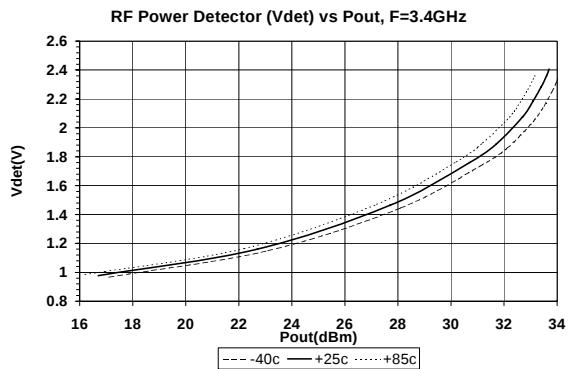
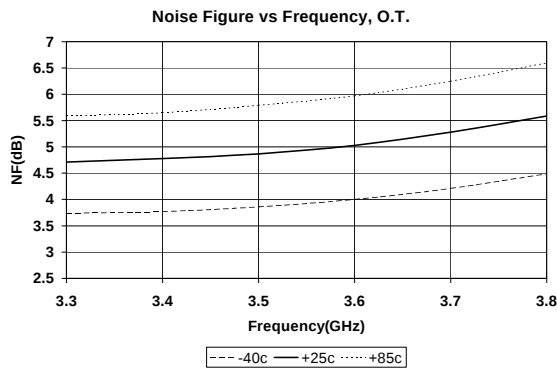
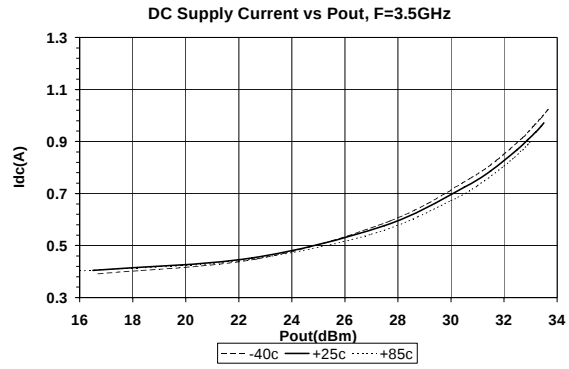
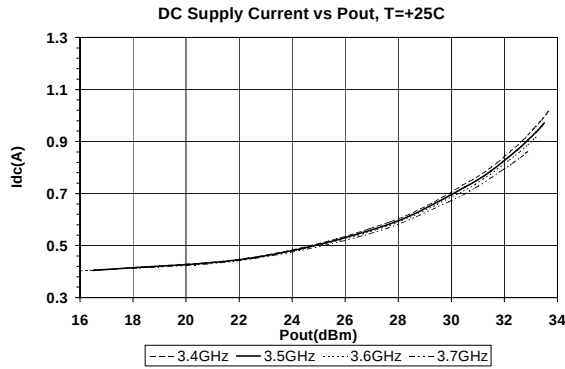
Measured 3.4-3.6 GHz, 5V Application Circuit Data ($V_{cc} = V_{pc} = 5.0V$, $I_q = 385mA$, $T=25C$)





Preliminary
SZP-3026Z 3.0-3.8GHz 2W Power Amp

Measured 3.4-3.6 GHz, 5V Application Circuit Data ($V_{cc} = V_{pc} = 5.0V$, $I_q = 385mA$, $T=25C$)



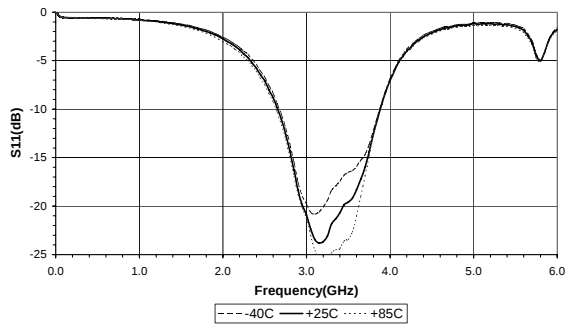


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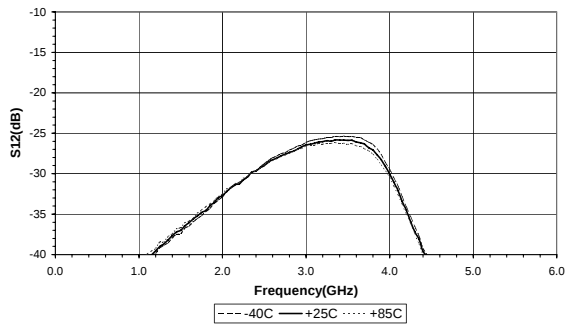
SZP-3026Z 3.0-3.8GHz 2W Power Amp

Measured 3.4-3.6 GHz, 5V Application Circuit Data ($V_{cc} = V_{pc} = 5.0V$, $I_q = 385mA$, $T=25C$)

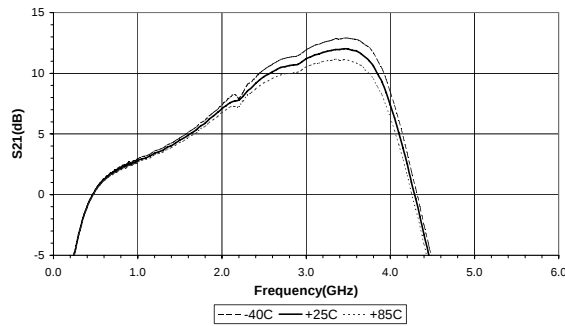
Broadband S11 - Input Return Loss



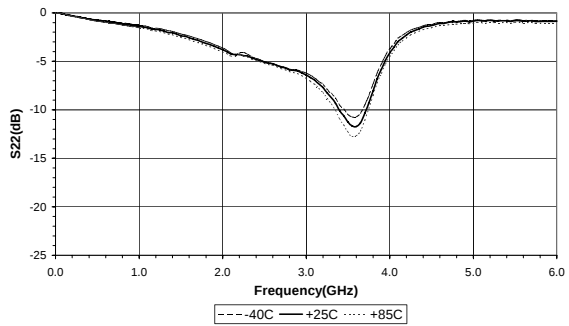
Broadband S12 - Reverse Isolation



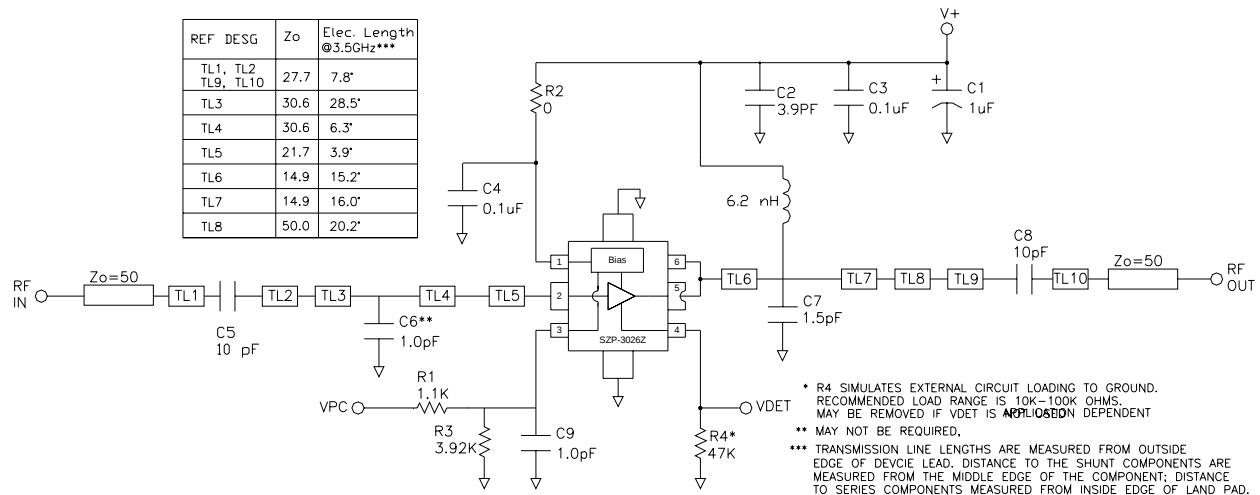
Broadband S21 - Forward Gain



Broadband S22 - Output Return Loss

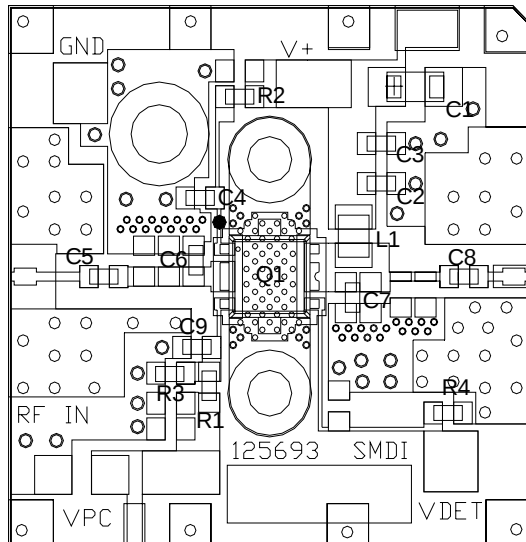


3.4-3.6 GHz Evaluation Board Schematic For $V^+ = V_{cc} = V_{pc} = 5.0V$, $I_q=385mA$



3.4-3.6GHz Evaluation Board Layout For $V^+ = V_{cc} = V_{pc} = 5.0V$, $I_q=385mA$

Board material GETEK, 10mil thick, Dk=3.9, 2 oz. copper



DESIG	DESCRIPTION	NOTES
Q1	SZP-3026Z	S0F-26
R1**	1.1K OHM, 0603 1%	0402 may be used
R2	0 OHM, 0603	"
R3**	3.92K OHM, 0603 1%	"
R4	47K OHM, 0603	"
C1	1uF 16V MLCC CAP	Tantalum ok for EVM performance. Use MLCC type for best IM3 levels.
C2	3.9pF CAP, 0603	NPO ROHM MCH185A3R9DK or equiv.
C3,4	0.1uF CAP, 0603	NPO, 0402 ok ROHM MCH184CN105K or equiv.
C5	10pF CAP, 0603	NPO, low ESR ATC 600S1R2CW250 or equiv.
C6	1.0pF CAP, 0603	NPO, 0402 ok ROHM MCH185A1R0DK or equiv.
C7	1.5pF CAP, 0603	NPO, low ESR ATC 600S1R2CW250 or equiv.
C8	10pF CAP, 0603	NPO, low ESR ATC 600S100JW250 or equiv.
C9	1.0pF CAP, 0603	NPO, 0402 ok ROHM MCH185A1R0DK or equiv.
L1	6.2nH IND, 0805	Coilcraft 0805HQ-6N2XJB

App circuit $V_{cc}=V_{pc}=6V$ resistor values

R1**	1.37K OHM, 0603 1%	0402 may be used
R3**	2.21K OHM, 0603 1%	"

** Replace resistors R1 and R3 for 6V operation

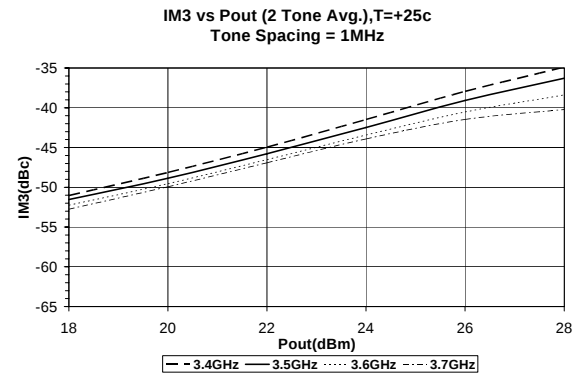
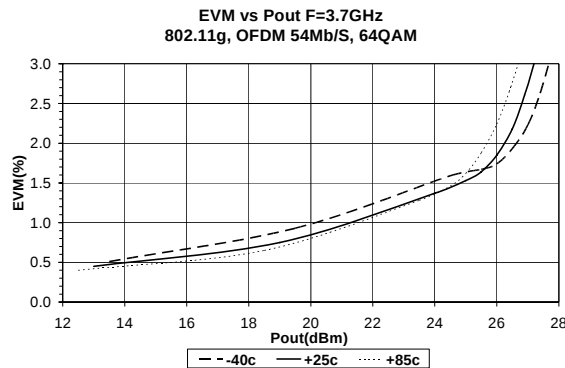
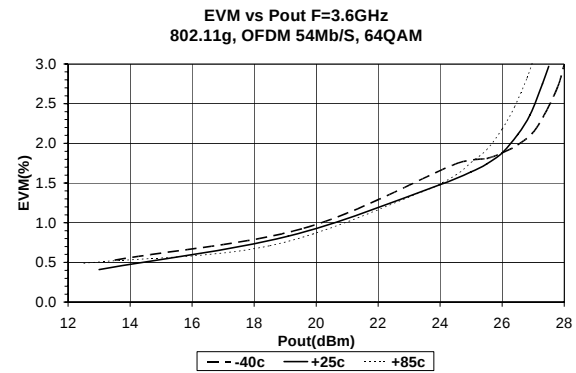
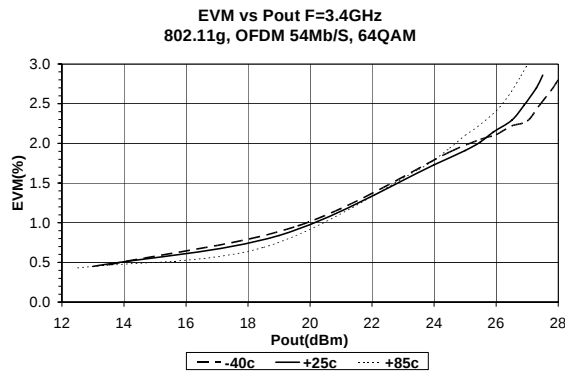
PCB NOTES: Do not use less than the recommended number of via holes under the device ground paddle.
RF layers thicker than .020 inches (0.5mm) not recommended.

Typical Performance with 6 Volt Application Circuit

Vcc=6V, Icq=326mA, * 802.11g 54Mb/s 64QAM

Parameter	Units	3.0GHz	3.3GHz	3.4GHz	3.5GHz	3.6GHz	3.7GHz	3.8GHz
Gain@Pout=26dBm	dB	11.5	11.5	11.3	11.3	11.3	11.4	11.2
P1dB	dBm	35.2	35.2	35.2	35.2	35.0	34.5	33.9
Pout @ 2.5% EVM*	dBm	27.0	27.0	27.0	27.1	27.0	26.9	26.2
Current @ Pout 2.5% EVM*	mA	529	529	523	513	501	487	467
Input Return Loss	dB	15.9	15.9	14.2	13.9	14.5	17.3	21.7
Output Return Loss	dB	8.7	8.7	10.3	12.0	13.5	12.8	10.2

Measured 3.4-3.6 GHz, 6V Application Circuit Data ($V_{cc} = V_{pc} = 6.0V$, $I_q = 326mA$, $T=25C$)

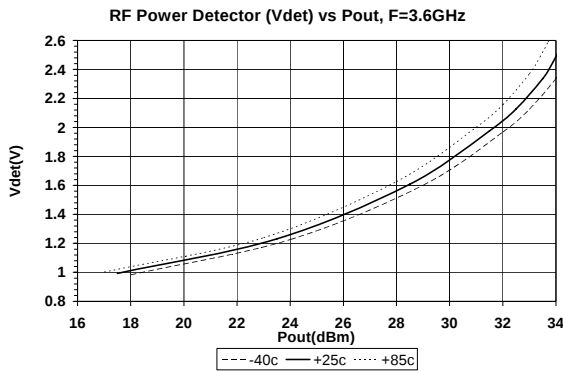
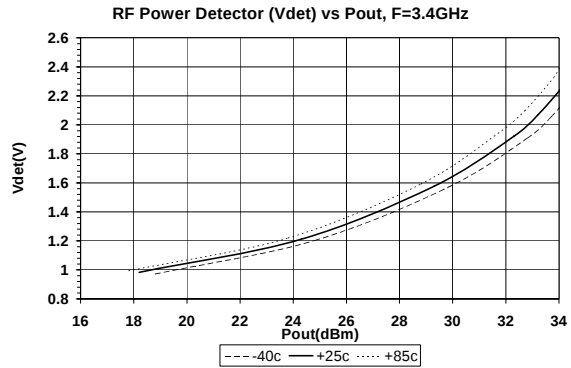
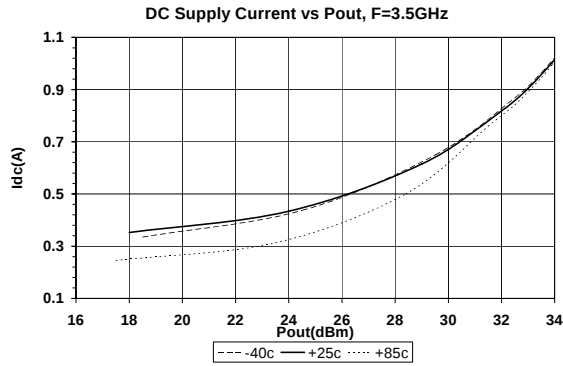
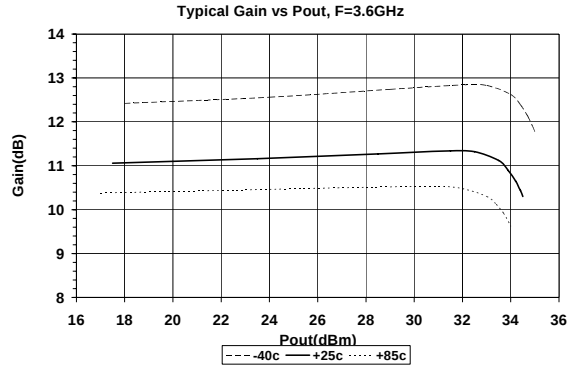
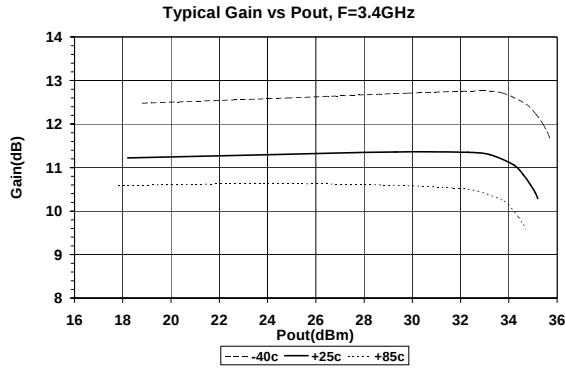




Preliminary

SZP-3026Z 3.0-3.8GHz 2W Power Amp

Measured 3.4-3.6 GHz, 6V Application Circuit Data ($V_{CC} = V_{PC} = 6.0V$, $I_q = 326mA$, $T=25C$)





Preliminary

SZP-3026Z 3.0-3.8GHz 2W Power Amp

Part Symbolization

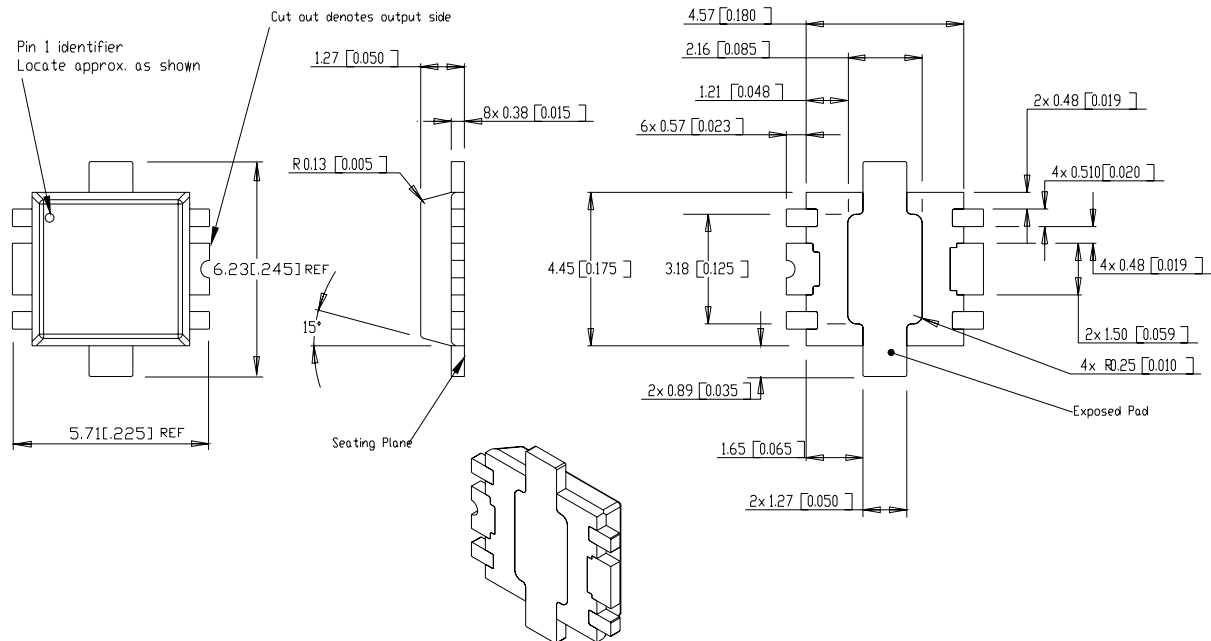
The part will be symbolized with a "SZP-3026Z" to designate it as a RoHS green compliant product. Marking designator will be on the top surface of the package.

Part Number Ordering Information

Part Number	Reel Size	Devices/Reel
SZP-3026Z*	13"	3000
SZP-3026Z EVB1	Evaluation Board	N/A

* Matte tin finish

Package Outline Drawing (dimensions in mm [in]):



Recommended Metal Land Pattern (dimensions in mm [in]):

